

DS26LV31T 3V Enhanced CMOS Quad Differential Line Driver

Check for Samples: DS26LV31T

FEATURES

- Industrial Product Meets TIA/EIA-422-B (RS-422) and ITU-T V.11 Recommendation
- Military Product Conforms to TIA/EIA-422-B (RS-422)
- Interoperable with Existing 5V RS-422 **Networks**
- Industrial and Military temperature Range
- Guaranteed V_{OD} of 2V min Over Operating **Conditions**
- **Balanced Output Crossover for Low EMI** (Typical Within 40 mV of 50% Voltage Level)
- Low Power Design (330 µW @ 3.3V static)
- ESD ≥ 7 kV on Cable I/O Pins (HBM)
- **Guaranteed AC Parameter:**
 - Maximum Driver Skew: 2 ns
 - Maximum Transition Time: 10 ns
- Pin Compatible with DS26C31
- Available in SOIC and CLGA Packaging

Standard Microcircuit Drawing (SMD) 5962-98584

DESCRIPTION

The DS26LV31T is a high-speed quad differential CMOS driver that meets the requirements of both TIA/EIA-422-B and ITU-T V.11. The CMOS DS26LV31T features low static I_{CC} of 100 µA MAX which makes it ideal for battery powered and power conscious applications.

Differential outputs have the same V_{OD} guarantee (≥2V) as the 5V version.

The EN and EN* inputs allow active Low or active High control of the TRI-STATE outputs. The enables are common to all four drivers. Protection diodes protect all the driver inputs against electrostatic discharge. Outputs have enhanced ESD protection providing greater than 7 kV tolerance. The driver and enable inputs (DI, EN, EN*) are compatible with low voltage LVTTL and LVCMOS devices.

Connection Diagram

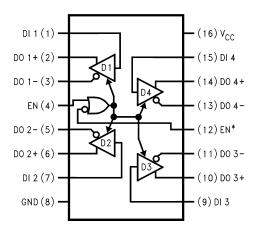


Figure 1. Dual-In-Line Package **Top View** See Package D (R-PDSO-G16)

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Truth Table⁽¹⁾

Enabl	es	Input	Outputs		
EN	EN*	DI	DO+	DO-	
L	L H		Z	Z	
All oth		L	L	Н	
combinati enable ir		Н	Н	L	

(1) L = Low logic state X = Irrelevant

H = High logic state

Z = TRI-STATE



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

Aboolato maximum ratingo	
Supply Voltage (V _{CC})	-0.5V to +7V
Enable Input Voltage (EN, EN*)	-0.5V to V _{CC} + 0.5V
Driver Input Voltage (DI)	-0.5V to V _{CC} + 0.5V
Clamp Diode Current	±20 mA
DC Output Current, per pin	±150 mA
Driver Output Voltage	
(Power Off: DO+, DO−)	−0.5V to +7V
Maximum Package Power Dissipation @+25°C	
D0016A Package	1226 mW
NAD0016A Package	1119 mW
Derate D0016A Package 9.8 mW/°C above +25°C	
Derate NAD0016A Package 7.5 mW/°C above +25°C	
Storage Temperature Range	−65°C to +150°C
Lead Temperature Range Soldering (4 sec.)	+260°C
ESD Ratings (HBM, 1.5 kΩ, 100 pF)	
Driver Outputs	≥7 kV
Other Pins	≥2.5 kV

 [&]quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics specifies conditions of device operation.

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage (V _{CC})	3.0	3.3	3.6	V
Operating Free Air Temperature Range (T _A)				
DS26LV31T	-40	+25	+85	°C
DS26LV31W	-55	+25	+125	°C
Input Rise and Fall Time			500	ns

⁽²⁾ If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.



Electrical Characteristics (1) (2)

Over supply voltage and operating temperature ranges, unless otherwise specified

	Parameter	Test Con	ditions	Pin	Min	Тур	Max	Units
V _{OD1}	Output Differential Voltage	R _L = ∞ (No Load)		DO+,		3.3	4	V
V _{OD2}	Output Differential Voltage	$R_L = 100\Omega$ (Figure 2)		DO-	2	2.6		V
ΔV_{OD2}	Change in Magnitude of Output Differential Voltage	I _O ≥ 20 mA			-400	7	400	mV
V_{OD3}	Output Differential Voltage	R _L = 3900Ω (V.11) Figure 2 and ⁽³⁾				3.2	3.6	V
V _{oc}	Common Mode Voltage	$R_L = 100\Omega$ (Figure 2)			1.5	2	V	
ΔV _{OC}	Change in Magnitude of Common Mode Voltage				-400	6	400	mV
l _{OZ}	TRI-STATE Leakage Current	V _{OUT} = V _{CC} or GND Drivers Disabled				±0.5	±20	μA
I _{SC}	Output Short Circuit Current	V _{OUT} = 0V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		-40	-70	-150	mA
	$V_{IN} = V_{CC} G$ $GND^{(4)}$	$V_{IN} = V_{CC}$ or GND (4)	$T_A = -55^{\circ}C$ to +125°C (5)		-30		-160	mA
I _{OFF}	Output Leakage Current	$V_{CC} = 0V$, $V_{OUT} = 3V$ or 6	6V			0.03	100	μΑ
		V _{CC} = 0V, V _{OUT} =	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			-0.08	-100	μΑ
		-0.25V	$T_A = -55$ °C to +125°C				-200	μΑ
V_{IH}	High Level Input Voltage			DI,	2.0		V_{CC}	V
V _{IL}	Low Level Input Voltage			EN,	GND		0.8	V
I _{IH}	High Level Input Current	$V_{IN} = V_{CC}$		EN*			10	μΑ
I _{IL}	Low Level Input Current	V _{IN} = GND			-10			μΑ
V_{CL}	Input Clamp Voltage	I _{IN} = −18 mA					-1.5	V
I _{CC}	Power Supply Current	No Load, V _{IN} (all) = V _{CC}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	V_{CC}			100	μΑ
		or GND	$T_A = -55$ °C to +125°C				125	μA

- Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except differential voltages V_{OD1}, V_{OD2}, V_{OD3}.
 All typicals are given for V_{CC} = +3.3V, T_A = +25°C.
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- Only one output shorted at a time. The output (true or complement) is configured High.
- This parameter does not meet the TIA/EIA-422-B specification.

Switching Characteristics - Industrial (1) (2)

Over supply voltage and -40°C to +85°C operating temperature range, unless otherwise specified

	Parameter	Test Conditions	Min	Тур	Max	Units
t _{PHLD}	Differential Propagation Delay High to Low	$R_L = 100\Omega$, $C_L = 50 pF$ (Figure 3 and Figure 4)	6	10.5	16	ns
t _{PLHD}	Differential Propagation Delay Low to High		6	11	16	ns
t _{SKD}	Differential Skew (same channel) t _{PHLD} - t _{PLHD}			0.5	2.0	ns
t _{SK1}	Skew, Pin to Pin (same device)			1.0	2.0	ns
t _{SK2}	Skew, Part to Part (3)			3.0	5.0	ns
t _{TLH}	Differential Transition Time Low to High (20% to 80%)			4.2	10	ns
t _{THL}	Differential Transition Time High to Low (80% to 20%)			4.7	10	ns
t _{PHZ}	Disable Time High to Z	(Figure 5 Figure 6)		12	20	ns
t _{PLZ}	Disable Time Low to Z			9	20	ns

- (1) f = 1 MHz, t_r and $t_f \le 6 \text{ ns}$, 10% to 90%.
- See TIA/EIA-422-B specifications for exact test conditions.
- Devices are at the same V_{CC} and within 5°C within the operating temperature range

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Switching Characteristics - Industrial (1) (2) (continued)

Over supply voltage and -40°C to +85°C operating temperature range, unless otherwise specified

	Parameter	Test Conditions	Min	Тур	Max	Units
t _{PZH}	Enable Time Z to High			22	32	ns
t _{PZL}	Enable Time Z to Low			22	32	ns
f _{max}	Maximum Operating Frequency ⁽⁴⁾		32			MHz

⁽⁴⁾ All channels switching, output duty cycle criteria is 40%/60% measured at 50%. This parameter is guaranteed by design and

Switching Characteristics - Military (1) (2)

Over supply voltage and -55°C to +125°C operating temperature range, unless otherwise specified

	Parameter	Test Conditions	Min	Max	Units
t _{PHLD}	Differential Propagation Delay High to Low	$R_L = 100\Omega$, $C_L = 50 \text{ pF}$ (Figure 3 Figure 4)	5	25	ns
t _{PLHD}	Differential Propagation Delay Low to High		5	25	ns
t _{SKD}	Differential Skew (same channel) t _{PHLD} - t _{PLHD}			5.0	ns
t _{SK1}	Skew, Pin to Pin (same device)			5.0	ns
t _{PHZ}	Disable Time High to Z	(Figure 5 Figure 6)		35	ns
t _{PLZ}	Disable Time Low to Z			35	ns
t _{PZH}	Enable Time Z to High			40	ns
t _{PZL}	Enable Time Z to Low			40	ns

 $[\]begin{array}{ll} \mbox{(1)} & \mbox{f} = 1 \mbox{ MHz, } t_r \mbox{ and } t_f \leq 6 \mbox{ ns, } 10\% \mbox{ to } 90\%. \\ \mbox{(2)} & \mbox{See TIA/EIA-422-B specifications for exact test conditions.} \end{array}$



PARAMETER MEASUREMENT INFORMATION

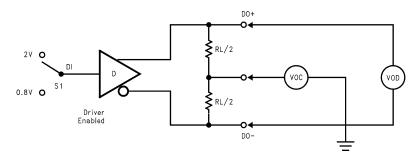


Figure 2. Differential Driver DC Test Circuit

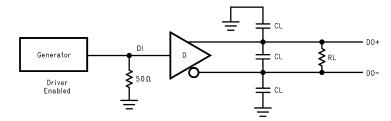
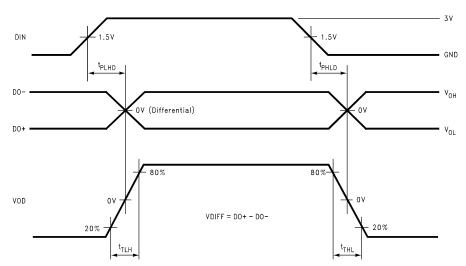


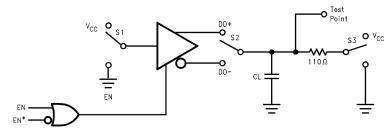
Figure 3. Differential Driver Propagation Delay and Transition Time Test Circuit



- A. Generator waveform for all tests unless otherwise specified: f = 1 MHz, Duty Cycle = 50% $Z_0 = 50\Omega$, $t_r \le 10$ ns, $t_f \le 10$
- B. C_L includes probe and fixture capacitance.

Figure 4. Differential Driver Propagation Delay and Transition Time Waveforms





If EN is the input, then $EN^* = High$ If EN* is the input, then EN = Low

Figure 5. Driver Single-Ended TRI-STATE Test Circuit

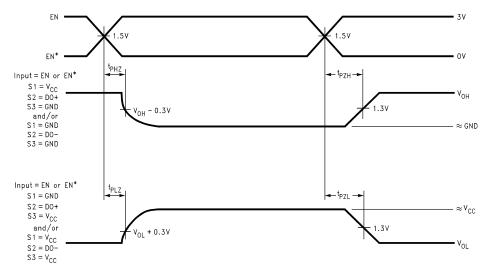


Figure 6. Driver Single-Ended TRI-STATE Waveforms



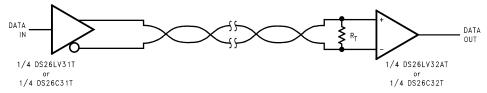
Typical Application Information

General application guidelines and hints for differential drivers and receivers may be found in the following application notes:

- AN-214
- AN-457
- AN-805
- AN-847
- AN-903
- AN-912
- AN-916

Power Decoupling Recommendations:

Bypass caps must be used on power pins. High frequency ceramic (surface mount is recommended) 0.1 µF in parallel with 0.01 µF at the power supply pin. A 10 µF or greater solid tantalum or electrolytic should be connected at the power entry point on the printed circuit board.



R_T is optional although highly recommended to reduce reflection.

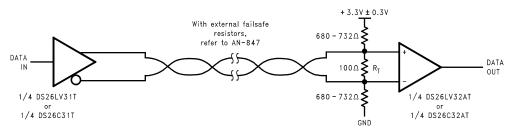


Figure 7. Typical Driver Connection

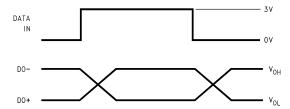


Figure 8. Typical Driver Output Waveforms

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REVISION HISTORY

Cł	hanges from Revision B (February 2013) to Revision C	Pag	е
•	Changed layout of National Data Sheet to TI format		7





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
DS26LV31TM	ACTIVE	SOIC	D	16	48	TBD	Call TI	Call TI	-40 to 85	DS26LV31 TM	Samples
DS26LV31TM/NOPB	ACTIVE	SOIC	D	16	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS26LV31 TM	Samples
DS26LV31TMX	ACTIVE	SOIC	D	16	2500	TBD	Call TI	Call TI	-40 to 85	DS26LV31 TM	Samples
DS26LV31TMX/NOPB	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS26LV31 TM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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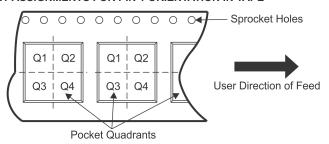
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS26LV31TMX	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1
DS26LV31TMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

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*All dimensions are nominal

Device	Device Package Type Package D		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS26LV31TMX	SOIC	D	16	2500	367.0	367.0	35.0
DS26LV31TMX/NOPB	SOIC	D	16	2500	367.0	367.0	35.0

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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